

SiC Schottky Barrier Diode

V_R	650V
I _F	10A
Q_{C}	24nC

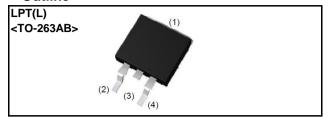
Features

- 1) Low forward voltage
- 2) Negligible recovery time/current
- 3) Temperature independent switching behavior
- 4) High surge current capability
- 5) Low leakage current

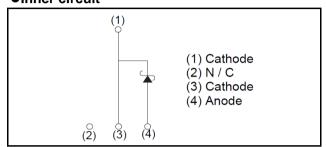
Applications

- Switch Mode Power Supply
- Uninterruptible Power Supply
- ·Solar Inverter
- Motor Drive
- Air Conditioner
- •EV Charger

Outline



•Inner circuit



Packaging specifications

	ging opcomoduone	
	Packaging	Embossed tape
	Reel size (mm)	330
Tuno	Tape width (mm)	24
Туре	Basic ordering unit (pcs)	1.000
	Packing code	TLL
	Marking	SCS310AJ

● Absolute maximum ratings (T_i = 25°C)

Parameter		Symbol	Value	Unit
Reverse voltage (repetitive peak)		V_{RM}	650	V
Reverse voltage (D0	C)	V _R	650	V
Continuous forward	current (T _c = 135°C)	I _F	10	А
Surge non-	PW=10ms sinusoidal, T _j =25°C		82	А
repetitive forward	PW=10ms sinusoidal, T _j =150°C	I _{FSM}	69	А
current	PW=10μs square, T _j =25°C		300	А
Repetitive peak forward current		I _{FRM}	47 * ¹	А
1≦PW≦10ms, T _j =25°C		\int i ² dt	33	A ² s
i ² t value	1≦PW≦10ms, T _j =150°C	J i-at	23	A ² s
Total power disspation		P_{D}	75 ^{*2}	W
Junction temperature		T _j	175	°C
Range of storage temperature		T_{stg}	-55 to +175	°C

^{*1} T_c =100°C, T_j =150°C, Duty cycle=10% *2 T_c =25°C

●Electrical characteristics (T_i = 25°C)

Parameter	Symbol	Conditions	Values			Linit
			Min.	Тур.	Max.	Unit
DC blocking voltage	V_{DC}	I _R =50μA	650	-	-	V
	V _F	I _F =10A,T _j =25°C	-	1.35	1.50	V
Forward voltage		I _F =10A,T _j =150°C	-	1.44	1.71	V
		I _F =10A,T _j =175°C	-	1.50	-	V
Reverse current	I _R	V _R =650V,T _j =25°C	=	0.03	50	μА
		V _R =650V,T _j =150°C	-	2	200	μΑ
		V _R =650V,T _j =175°C	-	6	-	μА
Total capacitance	С	V _R =1V,f=1MHz	=	500	-	pF
		V _R =650V,f=1MHz	-	46	-	pF
Total capacitive charge	Q _C	V _R =400V,di/dt=350A/μs	-	24	-	nC
Switching time	t _C	V _R =400V,di/dt=350A/μs	=	15	-	ns
Non-repetetive Avaranche Energy	E _{ava}	L=1mH	-	130	-	mJ

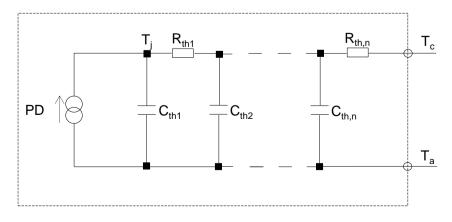
●Thermal characteristics

Parameter	Symbol	Conditions	Values			Unit
			Min.	Тур.	Max.	Offic
Thermal resistance	R _{th(j-c)}	-	ı	1.4	2.0	°C/W

●Typical Transient Thermal Characteristics

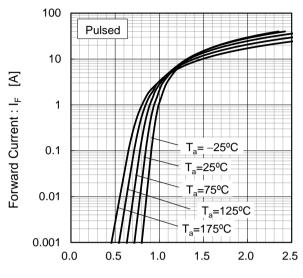
Symbol	Value	Unit
R _{th1}	2.06E-01	
R _{th2}	1.07E+00	K/W
R _{th3}	1.22E-01	

Symbol	Value	Unit
C_{th1}	1.92E-04	
C_{th2}	2.30E-03	Ws/K
C _{th3}	4.39E-02	



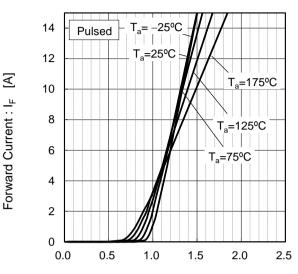
•Electrical characteristic curves

Fig.1 V_F - I_F Characteristics



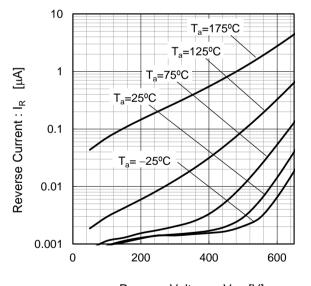
Forward Voltage : V_F [V]

Fig.2 V_F - I_F Characteristics



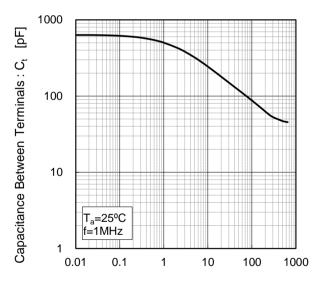
Forward Voltage : V_F [V]

Fig.3 V_R - I_R Characteristics



Reverse Voltage : V_R [V]

Fig.4 V_R-C_t Characteristics



Reverse Voltage : V_R [V]

Electrical characteristic curves

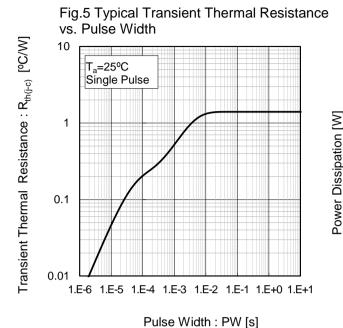


Fig.6 Power Dissipation

80

70

60

40

30

20

10

0

25

50

75

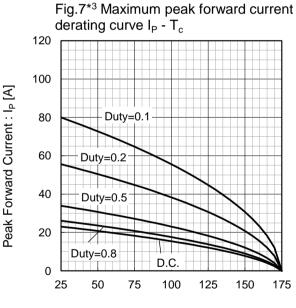
Case Temperature : T_c [°C]

125

150

175

100



Case Temperature : T_c [°C]
*3 Based on max Vf, max R_{th(j-c)}
Valid for switching of above 10kHz, excluding D.C. curve.

derating curve I_P - T_c (Not guaranteed) 120 Duty=0.1 100 Duty=0.2 80 60 Duty=0.5 40 20 Duty=0.8 D.C. 0 25 50 75 100 125 150 175

Fig.8*4 Typical peak forward current

Case Temperature : T_c [°C] *4 Based on typ Vf, typ R_{th(j-c)} Typical value, not guaranteed Valid for switching of above 10kHz, excluding D.C. curve

Peak Forward Current : I_P [A]

Electrical characteristic curves

Fig.9 Surge non-repetitive forward current vs. Pulse width (Sinusoidal waveform)

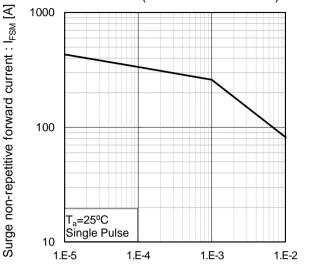
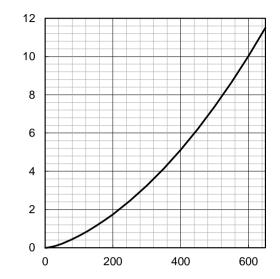


Fig.10 Typical capacitance store energy



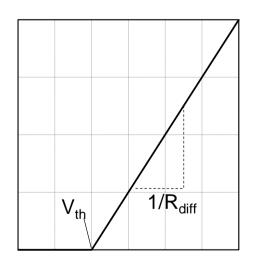
Capacitance stored energy : $E_{c}[\mu J]$

Reverse Voltage : V_R [V]

Symplified forward characteristic model

Fig.11 Equivalent forward current curve

Pulse Width: PW [s]



Forward Voltage: V_F

$$V_F = V_{th} + R_{diff} I_F$$

$$\begin{aligned} &V_{th} \left(\ T_{j} \ \right) = a_{0} + a_{1} \, T_{j} \\ &R_{diff} \left(\ T_{j} \ \right) = b_{0} + b_{1} \, T_{j} + b_{2} \, T_{j}^{2} \end{aligned}$$

Symbol	Typical Value	Unit
a ₀	9.66E-01	V
a ₁	-1.10E-03	V/°C
b ₀	3.52E-02	Ω
b ₁	7.46E-05	Ω/°C
b ₂	7.68E-07	$\Omega/^{\circ}C^{2}$

 $T_i \text{ in } {}^{\circ}\text{C}$; -55 ${}^{\circ}\text{C}$ < T_i < 175 ${}^{\circ}\text{C}$; I_F < 20 A

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Forward Current: IF

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